



July 1994
Revised April 1999

74VHC27

Triple 3-Input NOR Gate

General Description

The VHC27 is an advanced high speed CMOS 3-Input NOR Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This cir-

cuit prevents device destruction due to mismatched supply and input voltages.

Features

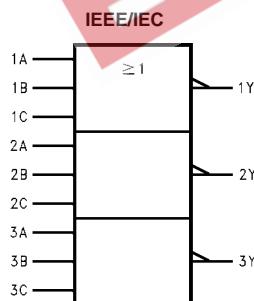
- High speed: $t_{PD} = 4.1$ ns (typ) at $T_A = 25^\circ\text{C}$
- Low power dissipation: $I_{CC} = 2 \mu\text{A}$ (max) at $T_A = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\%$ V_{CC} (min)
- Power down protection is provided on all inputs
- Low noise: $V_{OLP} = 0.8\text{V}$ (max)
- Pin and function compatible with 74HC27

Ordering Code:

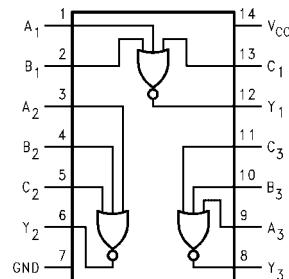
| Order Number | Package Number | Package Description |
|--------------|----------------|---|
| 74VHC27M | M14A | 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow |
| 74VHC27SJ | M14D | 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide |
| 74VHC27MTC | MTC14 | 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide |
| 74VHC27N | N14A | 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide |

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Connection Diagram



Pin Descriptions

| Pin Names | Description |
|--------------------------|-------------------|
| A_n, B_n, C_n Y_n | Inputs Outputs |

Truth Table

| A | B | C | Y |
|---|---|---|---|
| H | X | X | L |
| X | H | X | L |
| X | X | H | L |
| L | L | L | H |

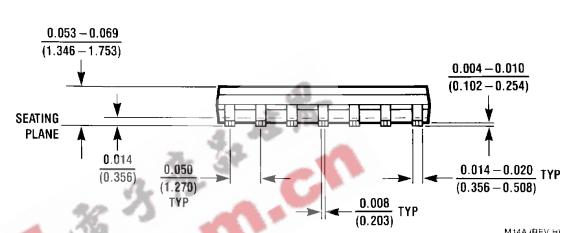
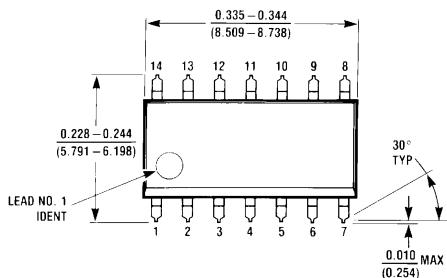
X = Don't Care

| Absolute Maximum Ratings (Note 1) | | | | | | | Recommended Operating Conditions (Note 2) | |
|--|---|------------------|--------------------------|----------------------|----------------------|-------------------|--|--|
| Supply Voltage (V_{CC}) | | | -0.5V to +7.0V | | | | Supply Voltage (V_{CC}) | 2.0V to +5.5V |
| DC Input Voltage (V_{IN}) | | | -0.5V to +7.0V | | | | Input Voltage (V_{IN}) | 0V to +5.5V |
| DC Output Voltage (V_{OUT}) | | | -0.5V to $V_{CC} + 0.5V$ | | | | Output Voltage (V_{OUT}) | 0V to V_{CC} |
| Input Diode Current (I_{IK}) | | | -20 mA | | | | Operating Temperature (T_{OPR}) | -40°C to +85°C |
| Output Diode Current (I_{OK}) | | | ±20 mA | | | | Input Rise and Fall Time (t_r, t_f) | |
| DC Output Current (I_{OUT}) | | | ±25 mA | | | | $V_{CC} = 3.3V \pm 0.3V$ | 0 ns/V ~ 100 ns/V |
| DC V_{CC}/GND Current (I_{CC}) | | | ±50 mA | | | | $V_{CC} = 5.0V \pm 0.5V$ | 0 ns/V ~ 20 ns/V |
| Storage Temperature (T_{STG}) | | | -65°C to +150°C | | | | | |
| Lead Temperature (T_L) (Soldering, 10 seconds) | | | 260°C | | | | | |
| Note 1: Absolute Maximum Ratings are values beyond which the device may be damaged or have its useful life impaired. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications. | | | | | | | Note 2: Unused inputs must be held HIGH or LOW. They may not float. | |
| DC Electrical Characteristics | | | | | | | | |
| Symbol | Parameter | V_{CC} (V) | $T_A = 25^\circ C$ | | | Units | Conditions | |
| | | | Min | Typ | Max | | | |
| V_{IH} | HIGH Level Input Voltage | 2.0 3.0 - 5.5 | 1.50 0.7 V_{CC} | | 1.50 0.7 V_{CC} | V | | |
| V_{IL} | LOW Level Input Voltage | 2.0 3.0 - 5.5 | | 0.50 0.3 V_{CC} | 0.50 0.3 V_{CC} | V | | |
| V_{OH} | HIGH Level Output Voltage | 2.0 | 1.9 | 2.0 | 1.9 | V | $V_{IN} = V_{IH}$ or V_{IL} | $I_{OH} = -50 \mu A$ $I_{OH} = -4 mA$ $I_{OH} = -8 mA$ |
| | | 3.0 | 2.9 | 3.0 | 2.9 | | | |
| | | 4.5 | 4.4 | 4.5 | 4.4 | | | |
| | | 3.0 | 2.58 | | 2.48 | | | |
| V_{OL} | LOW Level Output Voltage | 4.5 | 3.94 | | 3.80 | V | $V_{IN} = V_{IH}$ or V_{IL} | $I_{OL} = 50 \mu A$ $I_{OL} = 4 mA$ $I_{OL} = 8 mA$ |
| | | 2.0 | | 0.0 | 0.1 | | | |
| | | 3.0 | | 0.0 | 0.1 | | | |
| | | 4.5 | | 0.0 | 0.1 | | | |
| I_{IN} | Input Leakage Current | 0 - 5.5 | | ±0.1 | | μA | $V_{IN} = 5.5V$ or GND | |
| | | | | | ±1.0 | | | |
| I_{CC} | Quiescent Supply Current | 5.5 | | 2.0 | | μA | $V_{IN} = V_{CC}$ or GND | |
| Noise Characteristics | | | | | | | | |
| Symbol | Parameter | V_{CC} (V) | $T_A = 25^\circ C$ | | Units | Conditions | | |
| | | | Typ | Limits | | | | |
| V_{OLP} (Note 3) | Quiet Output Maximum Dynamic V_{OL} | 5.0 | 0.3 | 0.8 | V | $C_L = 50 pF$ | | |
| V_{OLV} (Note 3) | Quiet Output Minimum Dynamic V_{OL} | 5.0 | -0.3 | -0.8 | V | $C_L = 50 pF$ | | |
| V_{IHD} (Note 3) | Minimum HIGH Level Dynamic Input Voltage | 5.0 | | 3.5 | V | $C_L = 50 pF$ | | |
| V_{ILD} (Note 3) | Maximum LOW Level Dynamic Input Voltage | 5.0 | | 1.5 | V | $C_L = 50 pF$ | | |
| Note 3: Parameter guaranteed by design. | | | | | | | | |

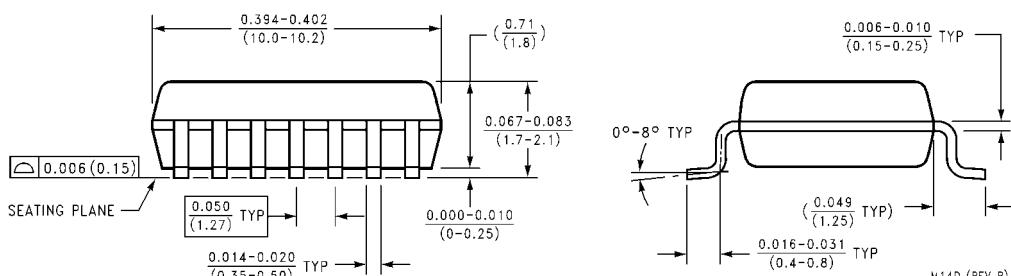
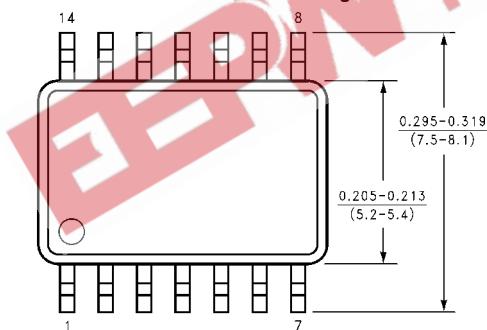
AC Electrical Characteristics

| Symbol | Parameter | V_{CC} (V) | $T_A = 25^\circ C$ | | | $T_A = -40^\circ C \text{ to } +85^\circ C$ | | Units | Conditions |
|------------------------|----------------------------------|-----------------|--------------------|-----|------|---|------|-------|------------------------|
| | | | Min | Typ | Max | Min | Max | | |
| t_{PHL} t_{PLH} | Propagation Delay | 3.3 ± 0.3 | | 6.2 | 8.8 | 1.0 | 10.5 | ns | $C_L = 15 \text{ pF}$ |
| | | | | 8.7 | 12.3 | 1.0 | 14.0 | | $C_L = 50 \text{ pF}$ |
| | | 5.0 ± 0.5 | | 4.1 | 5.9 | 1.0 | 7.0 | ns | $C_L = 15 \text{ pF}$ |
| | | | | 5.6 | 7.9 | 1.0 | 9.0 | | $C_L = 50 \text{ pF}$ |
| C_{IN} | Input Capacitance | | | 4 | 10 | | 10 | pF | $V_{CC} = \text{Open}$ |
| C_{PD} | Power Dissipation Capacitance | | | 20 | | | | pF | (Note 4) |

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC} (\text{opr.}) = C_{PD} * V_{CC} * f_{IN} + I_{CC}/3$ (per gate).

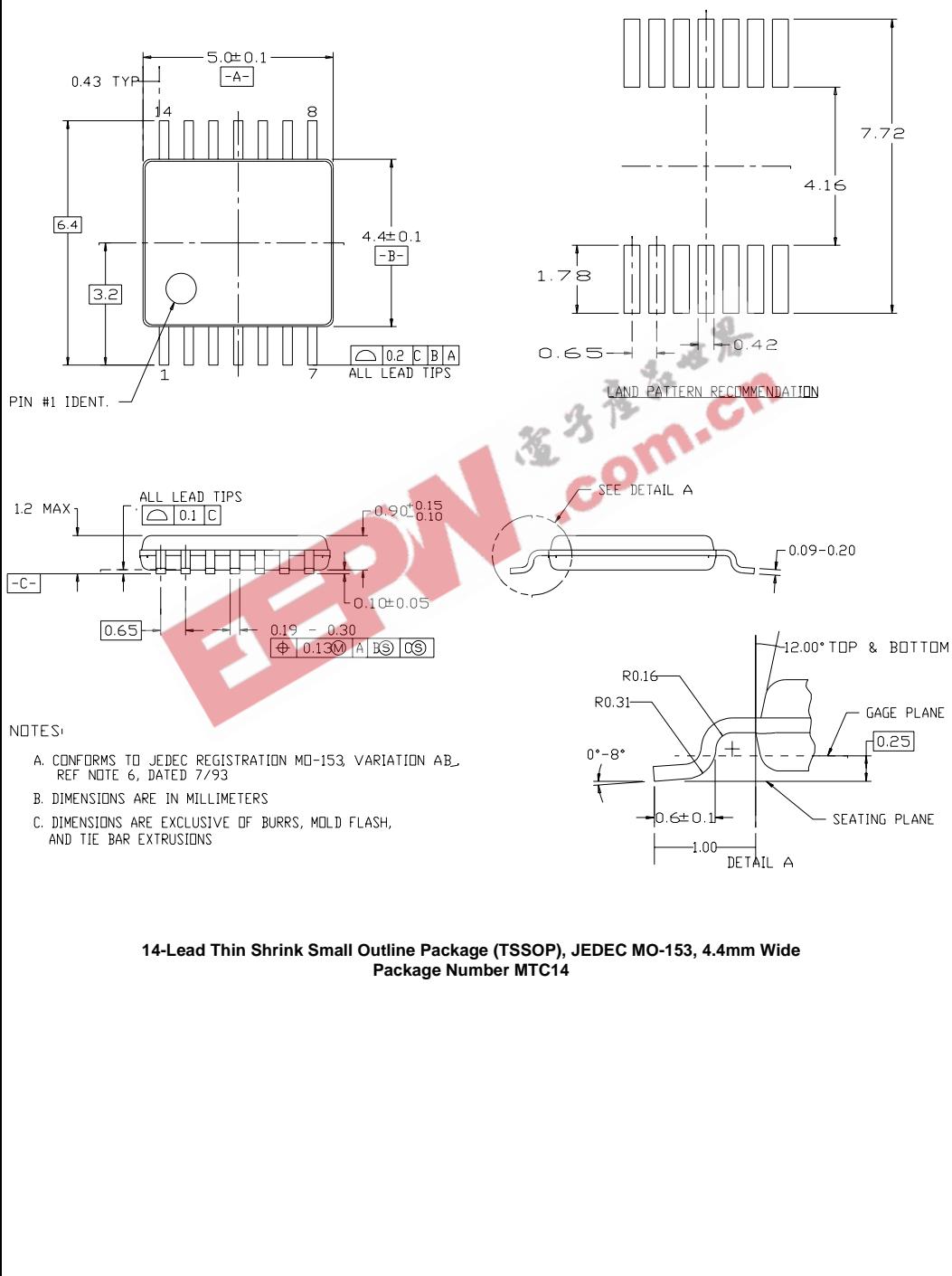
Physical Dimensions inches (millimeters) unless otherwise noted


**14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150 Narrow
Package Number M14A**



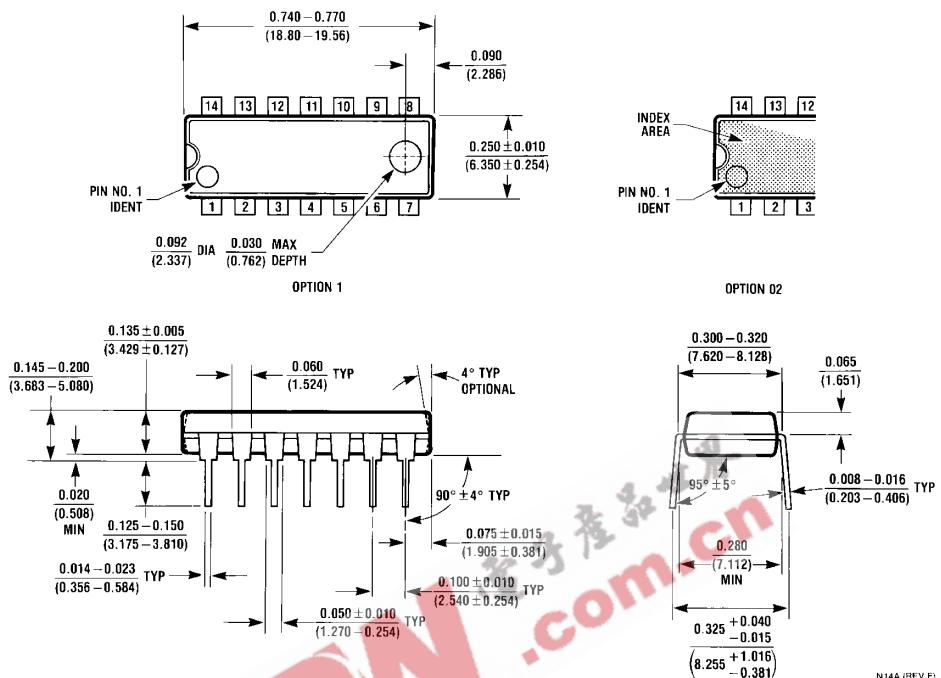
**14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M14D**

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



74VHC27 Triple 3-Input NOR Gate

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



**14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide
Package Number N14A**

N14A (REV F)

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